

Pending Active

- L1: (334) stack \$4 (amine(\$4) adj (metal adj (substrate base carrier)))
- L2: (11373958) (area region section portion segment part)
- L3: (3176501) layer
- L4: (6268909) second different another
- L5: (4842518) upper top
- L6: (B819260) 4 5
- L7: (464805) 4 adj 2
- L8: (238881) 8 adj 3
- L9: (2461) 7 with 8
- L10: (0) 1 same 9
- L11: (0) 1 same 7
- L12: (7) 1 same 8
- L13: (11) 1 and 7
- L14: (1810) (257/99).CCLS.
- L15: (0) 14 and 1
- L16: (0) 14 and 9

 Failed Saved

- (1) 09/948877
- (1736) "KONINKLIJKE PHILIPS".as.
- (2) 10/605757
- (0) 10/697510
- (0) 10/697510
- (0) 10/697810

ID	Inventor	Document Issue	Title	Current	Correct	XRef	Reviewed	S	C	P	R	F	E	Y	Z	Image	Date	P
1	<input type="checkbox"/> Chen, Tzer-P	US 6380564 20020.9	Semiconductor light emitting device	257/99	257/94			<input checked="" type="checkbox"/>	US 6380564									
2	<input type="checkbox"/> Schlaiss, And	US 5029518 19890.9	Circuit board and method	257/712	257/415			<input checked="" type="checkbox"/>	US 5029518									
3	<input type="checkbox"/> Kawasaki, Hi	US 5250819 19931.1	Light emitting device having stepped non-rectangular profile	257/88	257/773			<input checked="" type="checkbox"/>	US 5250819									
4	<input type="checkbox"/> Sagawa, Ios	US 4933601 19900.1	Light emitting diode array chip and method of manufacture	313/500	257/89			<input checked="" type="checkbox"/>	US 4933601									
5	<input type="checkbox"/> Kobayashi, Hi	US 4316208 19820.1	Light-emitting semiconductor device and method	257/88	257/618			<input checked="" type="checkbox"/>	US 4316208									
6	<input type="checkbox"/> Umeda, Jun-i	US 3813587 19740.7	LIGHT EMITTING DIODES OF THE INJECTION TYPE	257/79	257/103			<input checked="" type="checkbox"/>	US 3813587									

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Ready

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DBs: USPAT-US PGPUB-EPO-IPO-DERVENT-IGM-TDB Default operator: OR

Plurals Highlight all bit terms initially

14 and 9

Sept. 2007